



 Form PTO 1449	<b>ATTY. DOCKET NUMBER</b> <b>AETE.0004</b>	<b>SERIAL NUMBER</b> <b>10/724,149</b>
<b>APPLICANT</b> <b>KUSUNOKI ET AL.</b>		
<b>FILING DATE</b> <b>December 1, 2003</b>		<b>GROUP</b> <b>2828</b>
<small>U.S. Department of Commerce Patent and Trademark Office</small>		
<small>Information Disclosure Statement by Applicant</small>		

## **U.S. Patent Documents**

### **Foreign Patent Documents**

Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)

hp	Yokoo, Kuniyoshi, et al., "Emission characteristics of metal-oxide-semiconductor electron tunneling cathode", J. Vac. Sci. Technol. B 11(2), American Vacuum Society, March/April 1993 PP429-432
hp	Negishi, Nobuyasu, et al, "High Efficiency Electron-Emission in Pt/SiO/Si/Al Structure", Japan Appl. Phys. Vol. 36, 1997, PP 939-941
hp	Okamoto, Shinji "Electronic discharge from EL thin film - Thin film cold cathode", NHK Science and Technical Research Laboratories", 1994, PP 592-595 (with English translation PP 1-4)
hp	Koshida, Nobuyoshi, "Luminescence of Porous Silicon Indirectly and directly exceeding the frame of the transition", Department of Electronic and Information Engineering, Faculty of Technology, Tokyo University of Agriculture and Technology, 1997 PP 437-443, (with English translation PP 1-10)

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